GR3281

.....23rd April 1999



DESCRIPTION

The GR3281 is a 32768 word by 8 bits (32K x 8) non-volatile CMOS Static Ram, fabricated from advanced silicon gate CMOS technology and a high reliability lithium power cell. The pin-out of the GR3281 conforms to the JEDEC standards and is fully compatible with normal static RAM. The power down circuit is fully automatic and is referenced at 4.5 volts. At this point the GR3281 is write protected by an internal inhibit function for Data Protection and the memory contents are retained by the lithium power source. Power down is very fast, this being essential for data integrity, taking a maximum of 15 μ S (15 microseconds) to power down from 5 volts to 0 volts. This is much faster than system power failure conditions. Therefore there are no special conditions required when installing the GR3281. The GR3281 can, without external power, retain data almost indefinitely. The limiting factor will be the shelf life of the lithium cell, which is typically ten years. It is possible that this figure may be extended in view of the extremely light duty imposed upon the cell.

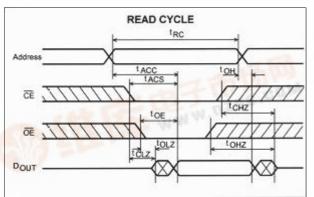
TECHNICAL DATA

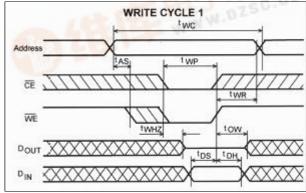
A	BSOLUTE MAX	CIMUM RATINGS	
Symbol	Min	Max	Units
Vdd	- 0.3	7.0	Volts
Vi/o	-0.3	Vdd + 0.3	Volts
Temp	- 20	+70	deg. C

	10000	OPER	RATING MO	DE	
CE	OE	WR	MODE	OUTPUT	ldd
H	X	X	Unsel.	Hi-Z	Deselected
L	Н	H	Unsel.	Hi-Z	Active
L	L	Н	Read	Dout	Active
L	X	L	Write	Din	Active

A14 A12 A7	1 2 3	28 27 26	Vdd WR A13	PIN DE	SIGNATIONS
A6 A5 A4 A3 A2 A1 A0 D0 D1 D2 GND	4 5 6 7 8 9 10 11 12 13	25 24 23 22 21 20 19 18 17 16	A8 A9 A11 OE A10 CE D7 D8 D5 D4 D3	Pin A0-A12 D0-D7 OE CE WR Vdd GND	Function Address I/P's Data in/out Output Enable Chip Enable Write Enable +5Volt Power Ground

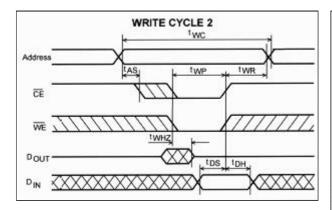
OPERATING CONDITIONS				
Symbol	Min	Тур	Max	Unit
Vdd	4.75	5.0	5.5	Volts
Vin (1)	2.2			Volts
Vin (0)			0.8	Volts
lin (any other pin)	- 1.0		+1.0	μA.
Vout $(1)(lout = -1mA)$) 2.4			Volts
Vout (0)(lout = +2mA			0.4	Volts
Idd (Active)		30		mA.
Idd (Deselected)		1.0		mA.
Tcycle			100	nS.
Cin (any pin)		10		pF

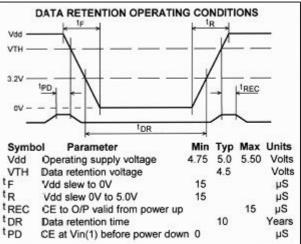




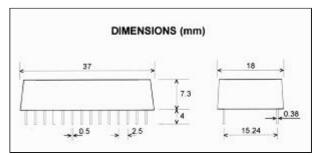


GR3281 Page 2 of 2





	Read Cycle	100nS	
Symbol	Parameter	Min	Max
RC	Read cycle time	100	
LACC	Access time		100
TACS	CE to output valid		100
^t OE	OE to output valid		50
CLZ	CE to output active	10	
^t OLZ	OE to output active	10	
^t OH	Output hold time	20	
CHZ	CE to output disable		35
^t OHZ	OE to output disable		35
	Write Cycle	100nS	
Symbol	Parameter	Min	Max
twc:	Write cycle time	100	
t _{WP}	Write pulse width	60	
^t AS	Address setup time	0	
twr:	Write recovery time	0	
^t WHZ	WR to output disable		35
WO	Output active from WR	10	
^t DS	Data setup time	35	
^t DH	Data HOLD TIME	0	
otes			
	e high during address transit	ions	
	urs during the overlap of a le		a low V



APPLICATION

When powered down, the GR3281 is transportable and data can be moved from system to system, this makes it ideal for program development, data collection in data loggers, program changes in process control, automation and robotics and user definable lookup tables, etc.

Additional information available through our technical sevices department.

